













Comment	Description ors none	Designator pag pto	Footprint per none	Quantity
υ 0	RES_0805 RES_1206	R49, R50 R34, R38	RES_0805 RES_1206	
1:1 1k	1:1 RES 0805	T5 R28, R29, R35, R42,	TRANSF_ACORE2 RES_0805	
1k	RES_0805	R43 R31, R65, R71, R72	RES_0805	
1k	RES_0805	R73, R74, R75, R76, R77, R78, R79, R80, R81, R82, R83, R84,	RESC2013X60X40NL20 T25	
în .	CAP 0805	R95 C47, C48, C72, C112,	CAP 0905	
in In	CAP_0805 CAP_0805	C115, C120 C122	6-0805_M	
1n8 1n8 100V	CAP_1206 CAP_1206	C105 C92, C94	CAP_1206 CAP_1206	
1N4148	1N4148	D4	1N4148	
TuF TuH	CAP_0805 IND_0805	C126, C128 L9, L17	CAP_0805 IND_0805	
1.2k	RES_0805	R53 C62, C74	RES_0805 CAP_0805	
1.5n	CAP_0805	C61	CAP_0805	
1.5uH 1.8uH	IND_0805 IND_0805	L14, L18, L25 L19, L26	IND_0805 IND_0805	
2k	RES_0805	R13	RESC2013X60X40NL20	
2uH	IND_0805 CAP 1206	L39, L47	T25 IND_0805 CAP 1206	
2.2uF 2.2uF 100V	CAP_1206	C91, C93	CAP_1206	
2.7uH 2.7uH	IND_0805 IND_0805	L22, L30, L31 L23, L27	IND_0805 IND_0805	
3.3n 3.3uH	CAP_0805 IND 0805	C75, C76	CAP_0805 IND 0805	
4.7uH	IND_0805	L24	IND_0805	
5.6uH 6.5-30p	IND_0905 TZC3P300A110	L29 C86, C87	IND_0805 5025[2010]	
6.8uH 8p	IND_0905 CAP_0905	L32 C16, C19	IND_0805 CAP_0805	
8T M2000HM 10*6*5	Transformer	TI	Rutrof 2	
8T M2000HM 10*6*5 8.2nH	Transformer	T3		
8.2uH	IND_0905 IND_0905	L34, L35, L36 L33	IND_0805 IND_0805	
10k	RES_0805	R37	RESC2013X60X40NL20 T25	
10k 10n	RES_1206 CAP_0805	R1 C121	RES_1206 6-0805_M	
10uF 25V	CAPAE_5.3x5.3h6.1	C129	CAPAE_5.3x5.3h6.1	
10uH 12p	Inductor CAP_0805	L37, L38, L43 C103	IND_FERRITE_CORE CAP_0805	
15p	CAP_0805	C18	CAP_0805	
15pF 18	CAP_0805 RES_1206	C17 R39	CAP_0805 RES_1206	
18p	CAP_1206 IND_0805	C123, C125	CAP_1206 IND_0805	
22nH 27nH	IND_0805	L48, L49, L51 L50	IND_0805	
27p	CAP_0805	C55, C104	CAP_0805 RESC2013X60X40NL20	
30k	RES_0805	R33, R45, R70	T25	
30k 33p	RES_0805 CAP_0805	R41, R57 C6	RES_0805 CAP_0805	
33p	CAP_1206	C124 C7. C101	CAP_1206	
39p 47p	CAP_0805 CAP_0805	C7, C101 C5, C13, C110	CAP_0805 CAP_0805	
47uF 25V	CAPAE_6.6x6.6h5.4		CAPAE_6.6x6.6h5.4	
51p	RES_1206 CAP_0805	R55, R56 C107	RES_1206 CAP_0805	
56 61p	RES_0805 CAP_0805	R27, R44 C12	RES_0805 CAP_0805	
68nH	Inductor	144 145	IND FERRITE CORE 1	
68p	CAP_0805	C102, C108	CAP_0805	
75p 82nH	CAP_0805 IND_0805	C11 L2, L41	CAP_0805 IND_0805	
uarii i	140_0000	C1, C2, C3, C4, C38,	IND_GGGG	
100n	CAP_0805	C80, C113, C114, C116, C117, C118, C130, C133, C134, C135, C136, C137, C139, C140, C141,	CAP_0805	
100n	CAP_0805	C142 C131	6-0805_M	
100n 100nH	CAP_1206 IND_0805	C81, C111	CAP_1206 IND_0805	
100p	CAP_0805	L3, L40 C9, C14, C22, C89	CAP_0805	
100p 110p	CAP_0805 CAP_0805	C127, C132 C8, C10	6-0805_M CAP_0805	
120 120p	RES_0805 CAP_0805	R32, R46 C15, C21, C88, C90	RES_0805 CAP_0805	
150nH	IND_0805	L5, L6, L42	IND_0805	
150p 180nH	CAP_0805 IND_0805	C20 L53, L54	CAP_0805 IND_0805	
180p	CAP_0805	C33, C34	CAP_0805 RES_0805	
200 220nH	IND_1206	L46	IND_1206	
270nH 270p	IND_0805	L1, L7	IND_0805	
300	CAP_0805 RES_1206	C24, C32, C45 R47, R48	CAP_0805 RES_1206	
330nH 330p	IND_0905 CAP_0905	L8, L10, L11, L52, L55 C23, C44, C46	IND_0805 CAP_0805	
470nH	IND_0805	L4, L15 C36, C60	IND_0805	
470p 510	CAP_0805 RES_0805	R36, R54	CAP_0805 RES_0805	
560	RES_0805	R3, R7, R8, R9, R10, R11, R12	RES_0805	
560nH	IND_0005	R11, R12 L12, L16	IND_0805	
560p 680nH	CAP_0805 IND_0805	C35 L20	CAP_0805 IND_0805	
680p	CAP_0805	C59	CAP_0805	
820nH 820p	IND_0805 CAP_0805	L13, L21 C58, C73	IND_0805 CAP_0805	
2027-07-SM-RPLF	2027-07-SM-RPLF	U18 AMP1_PWR,	200307SWRPLF	
51022-0200	51022-0200	AMP2_PWR,	51022-0200	l
ADC	SMA	FAN_OUT J2	31-5431	-
ADG904BRUZ-R	Integrated Circuit	U4, U15, U16, U17	SOP65P640X120-20N	
ADG918BRMZ	Integrated Circuit	UB, U10, U11, U12, U13, U14	SOP65P490X110-8N	
ADJ-1k ANT1	306J	R30, R40	306J 31,5431	
ANT1 ANT2	SMA SMA	J1 J5	31-5431 31-5431	
Axicom V23079 BAT46JFILM	Axicom V23079 Diode	K1 D1, D3	V23079 SOD2513X117N	
	BAV99 N-Channel Logic	D24	SOT23	
BAV99	rv-Channel Logic			
BAV99		1	FAIR-SOT23-3_V	l
BAV99		04 07 07		1
BAV99 BSS123	Level Enhancement Mode Field Effect Transistor, 1.7 V55	Q6, Q7, Q8	PAIR-30123-3_V	
BAV99	Level Enhancement Mode Field Effect Transistor, 1.7 V, -55 to 150 degC, 3-Pin SOT-23, RoHS, Tape	Q6, Q7, Q8	PAIR-30123-3_V	
BAV99 BSS123 DAC	Level Enhancement Mode Field Effect Transistor, 1.7 V, -55 to 150 degC, 3-Pin SOT-23, RoHS, Tape and Reel SMA	Q6, Q7, Q8	31-5431	
BSS123 DAC EXTERNAL	Level Enhancement Mode Field Effect Transistor, 1.7 V, -55 to 150 degC, 3-Pin SOT-23, RoHS, Tape and Reel SMA 2*5 PIN	J9 J3	31-5431 90131-0126	
BAV99 BSS123 DAC	Level Enhancement Mode Field Effect Transistor, 1.7 V, -55 to 150 degC, 3-Pin SOT-23, RoHS, Tape and Reel SMA	19	31-5431 90131-0126 90123	
BAV99 BSS123 DAC EXTERNAL IRLML9301	Level Enhancement Mode Field Effect Transistor, 1.7 V, -55 to 150 degC, 3-Pin SOT-23, RoHS, Tape and Reel SMA 2"5 PIN MOSFET	J9 J3	31-5431 90131-0126 S0123 1986/17-2 T0254P420X460X770-	
BASS123 DAC EXTERNAL IRLM/9001 IX/2 KT/981/120 LM1117/DT-5.0	Level Enhancement Mode Field Effect Transistor, 1.7 V, -55 to 150 degC, 3-Pin SOT-23, Rol4S, Tape and Reel SMA 2*5 PIN MOSFET IX2 Integrated Circuit Integrated Circuit	J9 J3 O2, O5 J8 R14	31-5431 90131-0126 90123 1966/17-2 10254P420X460X770- 2P 10228P991X238-3N	
DAC EXTERNAL IRJA(9301 IX2 KTYB1/120 LM1117DT.5.0	Level Enhancement Mode Field Effect Transistor, 1.7 V, -55 to 150 degC, 3-Pin SOT-28, RnHS, Tape and Reel SMA 2°5 PIN MOSFET JX2 Integrated Circuit Integrated Circuit Entegrated Circuit	J9 J3 G2, O5 J8 R14 U6	31-5431 90131-0126 507123 1996717-2 10258P420K460K770- 2P 10228P991X238-3N LTH117EST-AD	
BASS123 DAC EXTERNAL IRLM/9001 IX/2 KT/981/120 LM1117/DT-5.0	Level Enhancement Mode Field Effect Transistor, 1.7 V, -55 to 150 degC, 3-Pin SOT-22, RoHS, Tape and Reel SMA 2*5 PIN MOSFET JUZ Integrated Circuit Integrated Circuit Linearated Circuit 2*5 PIN Linearated Circuit Linearated Circuit Linearated Circuit Linearated Circuit Linearated Circuit Linearated Circuit Linearated Circuit	J9 J3 O2, O5 J8 R14	31-5431 90131-0126 50723 1996717-2 TOZSEP420K460K770- 2P TOZZEP991XZ38-3N LT111T/ST-ADJ 90131-0126 GFMSDP400M400M90-	
BAV99 DAC EXTERNAL IRIM 9301 IXI EXTERNAL EXTERNAL IXI EXTERNAL EXTERNAL EXTERNAL IXI EXTERNAL EXTERNAL	Level Enhancement Mode Flield Effect Transistor, 1.7 V55 to 150 degt, 2.7 V55 to 150 degt, 2.7 m of 2.7	J9 J3 Q2, Q5 J8 R14 U6 U5 J4 U9	31-5431 90131-0126 50123 1905/11-2 TO254P-420X460X770-2P TO228P-991X238-3N LT111781-ADJ 90131-0126 CFN50P-400X400X90- 21N SOT89	
BAV99 BSS123 DAC EXTERNAL IRLIA 9301 IX2 KTV81/120 LM117DT-5 0 LM117DT-5 0 LM117DT-5 0 LM117DT-5 0 FOR 1004 / SPF5189. ROOTM/S1	Level Enhancement Mode Field Enhancement Mode Field Enhancement Fransitor, 1,7 V, -55 to 150 deg/3, -75 SOL -25, RoHS, Tape and Reel MM MOSFET DIC Integrated Circuit Integrated Circuit Integrated Circuit Integrated Circuit Integrated Circuit Circ	J9 J3 Q2, Q5 J8 R14 U6 U5 J4	31-5431 90131-0126 50172 1906/11-2 102589420046000770_2P 10228999130238_3N LT11178T-ADJ 90131-0126 0FM5094000400090- 21N 50189 8D07MWS1	
DAC EXTERNAL IRI M. 9301 IXI KTHS1/120 LM1117DT-5.0 LT1117BT-ADJ MODIT-BROAMD PF4302 SROOM-51 SROOM-51 SROOM-51 SROOM-51 SROOM-51 SROOM-51 SROOM-51 SROOM-51	Level Enhancement Mode Field Enhancement Mode Field Enhancement Fransitor, 1.7 V, -55 to 150 deg/3. 276 SOL 150 deg/3. 275 SOL		31-5431 90131-0126 50123 1905/11-2 TO254P-420X460X770-2P TO228P-991X238-3N LT111781-ADJ 90131-0126 CFN50P-400X400X90- 21N SOT89	
BAV99 BSS123 DAC EXTERNAL IRLIA 9301 IX2 KTV81/120 LM117DT-5 0 LM117DT-5 0 LM117DT-5 0 LM117DT-5 0 FOR 1004 / SPF5189. ROOTM/S1	Level Enhancement Mode Field Enhancement Mode Field Enhancement Fransitor, 1.7 V, -55 to 150 deg/3. 276 SOL 150 deg/3. 275 SOL		31-5431 90131-0126 50172 1906/11-2 102589420046000770_2P 10228999130238_3N LT11178T-ADJ 90131-0126 0FM5094000400090- 21N 50189 8D07MWS1	
DAC EXTERNAL IRLM 9301 IX32 KT181/120 KT181/120 KT181/120 MOTHERDOARD PERDOARD PERDO	Level Enhancement Mode Field Enhancement Mode Field Enhancement Fransition, 1,7 V, -56 to 150 deg/3, -78 to 150 deg/3 to 15	39 13 02, OS 18 RTM U5 U5 U5 U9 O4 O1, O3 O2 U1, U3, U7	31-543] 9031-0726 9031-0726 9031-0726 9031-72 1906-17-2 102569-420X4606770- 2P 102569-940X458-3N 11117651-083-3N 11117651-083-3N 20180-083-3N S007805-083-3N	
DAC EXTERNAL IRI M. 9301 IXI KTHS1/120 LM1117DT-5.0 LT1117BT-ADJ MODIT-BROAMD PF4302 SROOM-51 SROOM-51 SROOM-51 SROOM-51 SROOM-51 SROOM-51 SROOM-51 SROOM-51	Level Enhancement Mode Field Effect Mode Field Effect Fransistor, 1.7 V, -55 to 150 deg/2. 25 Mode Field Field Field Mode Field Field Mode Field Field Mode	J9 J3 J3 J3 J3 J3 J3 J3 J3 J3 J4	21.5421 90131-0126 30123 90127 100259-420046000770 22P 90131-0126 90131-0126 07H50F4000400090 21N 90130-0126 90130 9	